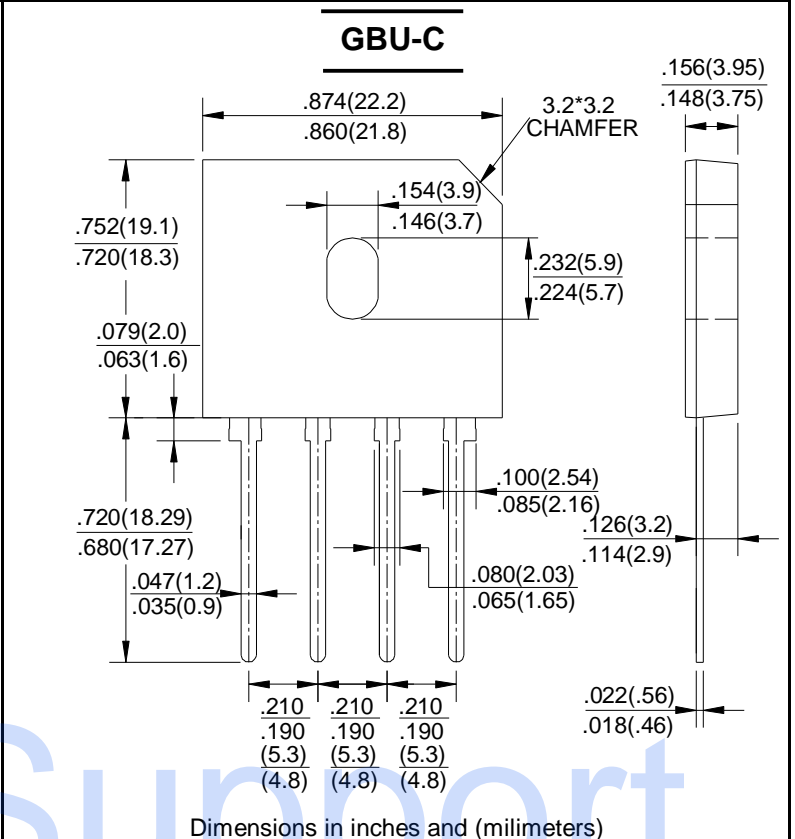


SILICON BRIDGE RECTIFIERS

REVERSE VOLTAGE - 50 to 1000Volts
 FORWARD CURRENT - 8.0 Amperes

- FEATURES**
- Surge overload rating -200 amperes peak
 - Ideal for printed circuit board
 - Reliable low cost construction utilizing molded plastic technique
 - Plastic material has U/L flammability classification 94V-0
 - Mounting position:Any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave ,60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

CHARACTERISTICS	SYMBOL	GBU 8005C	GBU 801C	GBU 802C	GBU 804C	GBU 806C	GBU 808C	GBU 810C	UNIT	
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	v	
Maximum RMS Voltage	V _{RMS}	30	70	140	280	420	560	700	v	
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	v	
Maximum Average Forward Rectified Current @ T _c =100°C (with heatsink Note 2) @ T _c =100°C (without heatsink)	I _(AV)	8.0						3.2		A
Peak Forward Surge Current 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	I _{FSM}	200								A
Maximum Forward Voltage at 4.0A DC	V _F	1.0								V
Maximum DC Reverse Current at Rated DC Blocking Voltage @ T _J =25°C @ T _J =125°C	I _R	10						500		uA
I ² t Rating for Fusing (t<8.3ms)	I ² t	166								A ² s
Typical Junction Capacitance Per Element (Note1)	C _J	60								pF
Typical Thermal Resistance (Note2)	R _{θJC}	2.2								°C/W
Operating Temperature Range	T _J	-55 to +125								°C
Storage Temperature Range	T _{STG}	-55 to +150								°C

NOTES: 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 2.Device mounted on 75mm*75mm*1.6mm cu plate heatsink.

FIG.1-FORWARD CURRENT DERATING CURVE

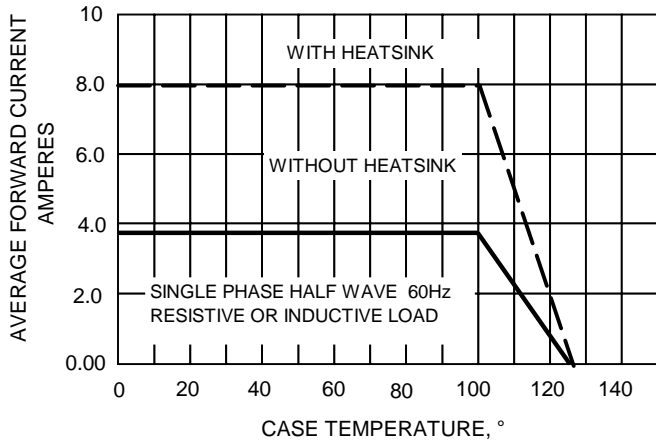


FIG.2-MAXIMUM NON-REPETITIVE SURGE CURRENT

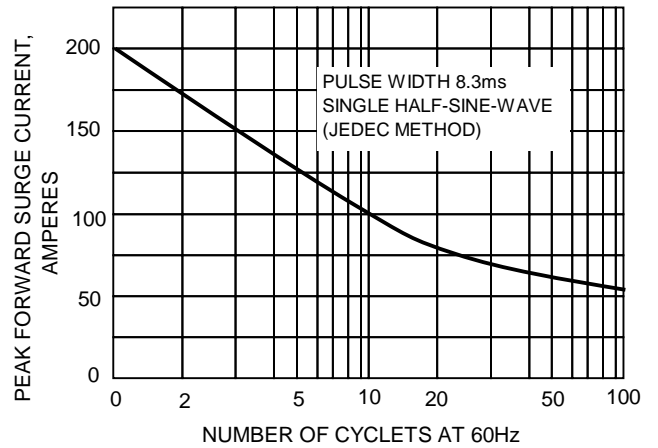


FIG.3-TYPICAL JUNCTION CAPACITANCE

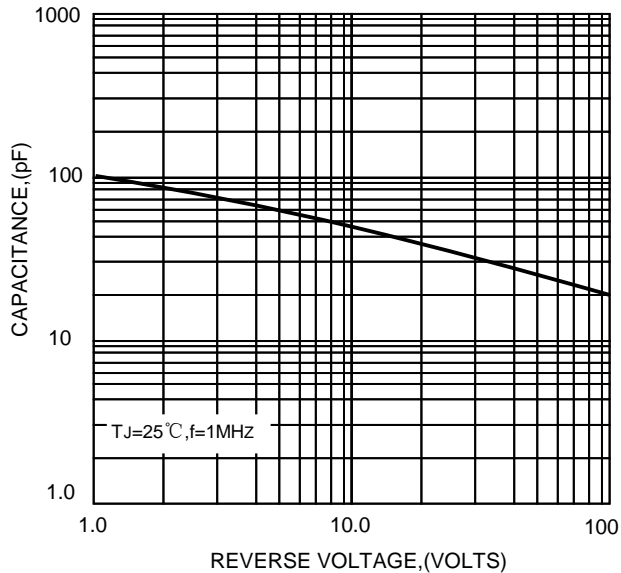


FIG.4-TYPICAL FORWARD CHARACTERISTICS

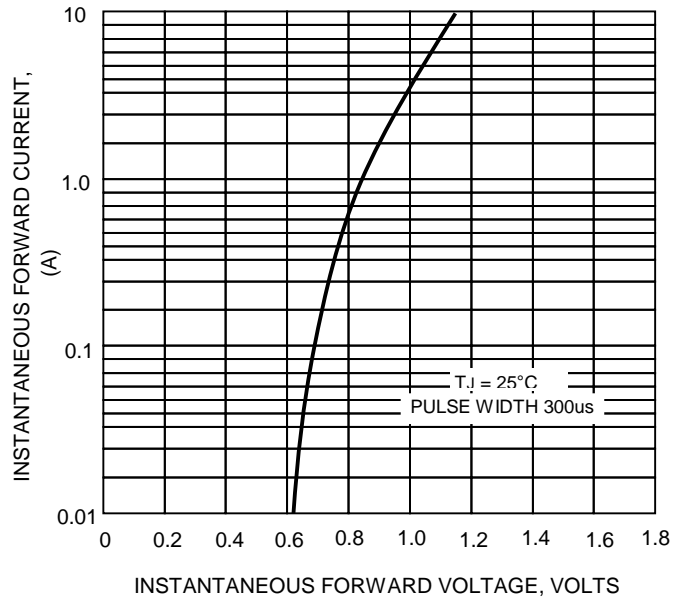


FIG.5-TYPICAL REVERSE CHARACTERISTICS

